7

6

D PACKAGE (TOP VIEW)

N1/COMP

ΙΝ– Π

IN+ **∏** 3

SLOS121B - NOVEMBER 1993 - REVISED MARCH 2001

П СОМР

V_{CC+}

OUT

OFFSET N2

- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input-Bias and Offset Currents
- Output Short-Circuit Protection
- Low Total Harmonic Distortion . . . 0.003% Typ
- Low Noise . . . $V_n = 18 \text{ nV}/\sqrt{\text{Hz}}$ Typ at f = 1 kHz
- High Input Impedance . . . JFET Input Stage
- Common-Mode Input Voltage Range Includes V_{CC+}
- Latch-Up-Free Operation
- High Slew Rate . . . 13 V/μs Typ

description

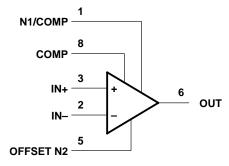
The JFET-input TL070 operational amplifier is designed as the lower-noise version of the TL080 amplifier with low input-bias and offset currents and fast slew rate. The low harmonic distortion and low noise make the TL070 ideally suited for high-fidelity and audio-preamplifier applications. This amplifier features JFET inputs (for high input impedance) coupled with bipolar output stages integrated on a single monolithic chip.

The TL070I device is characterized for operation from -40°C to 85°C.

AVAILABLE OPTIONS

		PACKAGE
TA	V _{IO} max AT 25°C	SMALL OUTLINE (D)
–40°C to 85°C	10 mV	TL070ID

logic symbol†



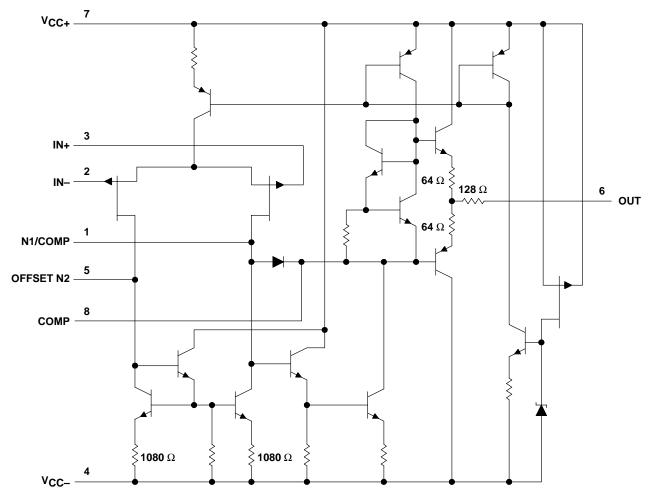
[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



schematic



All component values shown are nominal.

COMPONENT COUNT						
Transistors	13					
Diodes	2					
Resistors	10					
epi-FET	1					
JFET	2					

[†] Includes all bias and trim circuitry



TL070 JFET-INPUT OPERATIONAL AMPLIFIER

SLOS121B - NOVEMBER 1993 - REVISED MARCH 2001

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC+} (see Note 1)	18 V
Supply voltage, V _{CC}	–18 V
Differential input voltage, V _{ID} (see Note 2)	$\dots \dots \pm 30 \; V$
Input voltage, V _I (see Notes 1 and 3)	$\dots \dots \pm 15 \; V$
Duration of short-circuit current (see Note 4)	Unlimited
Package thermal impedance, θ_{JA} (see Note 5): D package	97°C/W
PW package	149°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T _{stg}	-65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.

- 2. Differential voltages are at IN+ with respect to IN-.
- 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
- 4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
- 5. The package thermal impedance is calculated in accordance with JESD 51-7.



SLOS121B - NOVEMBER 1993 - REVISED MARCH 2001

electrical characteristics, $V_{\mbox{CC}\pm}$ = ± 15 V (unless otherwise noted)

	PARAMETER	TEST C	ONDITIONS	T _A †	MIN	TYP	MAX	UNIT
Vio	Input offset voltage	V _O = 0,	Rs = 50 Ω	25°C		3	10	mV
VIO	input onset voltage	VO = 0,		Full range			13	111 V
$\alpha_{V_{IO}}$	Temperature coefficient of input offset voltage	$V_{O} = 0$,	$R_S = 50 \Omega$	Full range		18		μV/°C
	Input offset current	V _O = 0		25°C		5	100	pА
liO	input onset current			Full range			10	nA
IB	Input bias current [‡]	V _O = 0		25°C		65	200	pA
цВ	input bias current+	VO = 0		Full range			20	nA
VICR	Common-mode input voltage range			25°C	±11	-12 to 15		٧
		$\begin{aligned} R_L &= 10 \text{ k}\Omega \\ R_L &\geq 10 \text{ k}\Omega \\ R_L &\geq 2 \text{ k}\Omega \end{aligned}$		25°C	±12	±13.5		V
Vом	Maximum peak output voltage swing			Full range	±12			
					±10			
A _{VD}	Large-signal differential voltage amplification	$V_O = \pm 10 \text{ V}, R_L \ge 2 \text{ k}\Omega$		25°C	25	200		V/mV
AVD	Large signal differential voltage amplification			Full range	15			
B ₁	Unity-gain bandwidth			25°C		3		MHz
rį	Input resistance			25°C		1012		W
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR}$ $V_{O} = 0, R_{S}$		25°C	70	100		dB
k _{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC} = \pm 9 \text{ V to } \pm 15 \text{ V},$ $V_{O} = 0, R_{S} = 50 \Omega$		25°C	70	100		dB
ICC	Supply current	$V_O = 0$, No load		25°C		1.4	2.5	mA
V _{O1} /V _{O2}	Crosstalk attenuation	A _{VD} = 100		25°C		120	•	dB

[†] All characteristics are measured under open-loop conditions with zero common-mode voltage unless otherwise specified. Full range for T_A is -40°C to 85°C.

operating characteristics, $V_{CC\pm}$ = ± 15 V, T_A = $25^{\circ}C$

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR	Slew rate at unity gain	V _I = 10 V,	$R_L = 2 k\Omega$, $C_L = 100 pF$, See Figure 1	8	13		V/μs
	Rise-time overshoot factor	V _I = 20 mV,	P. – 2 kO C. – 100 pF See Figure 1		0.1		μs
t _r			$R_L = 2 \text{ k}\Omega$, $C_L = 100 \text{ pF}$, See Figure 1		20		%
\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	Equivalent input noise voltage	R _S = 20 Ω	f = 1 kHz		18		nV/√ Hz
V _n			f = 10 Hz to 10 kHz		4		μV
In	Equivalent input noise current	$R_S = 20 \Omega$,	f = 1 kHz		0.01		pA/√ Hz
THD	Total harmonic distortion	$V_{O(rms)} = 10 V,$	$R_{\mbox{\scriptsize S}} \leq 1 \ k \Omega, R_{\mbox{\scriptsize L}} \geq 2 \ k \Omega, \qquad f = 1 \ k Hz \label{eq:rescaled}$		0.003		%

[‡] Input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive as shown in Figure 5. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

APPLICATION INFORMATION

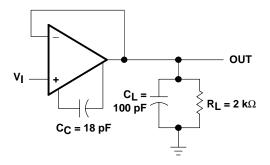


Figure 1. Unity-Gain Amplifier

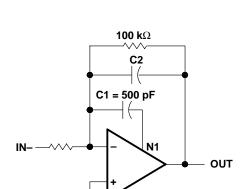


Figure 3. Feed-Forward Compensation

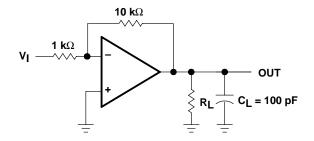


Figure 2. Gain-of-10 Inverting Amplifier

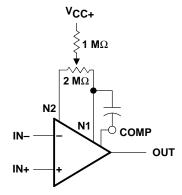


Figure 4. Input Offset Voltage Null Circuit

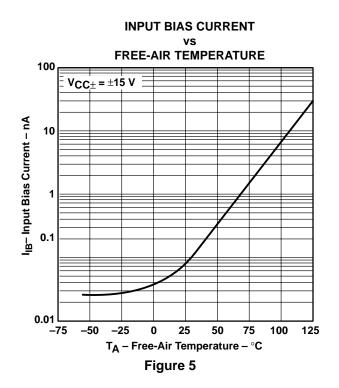
TYPICAL CHARACTERISTICS

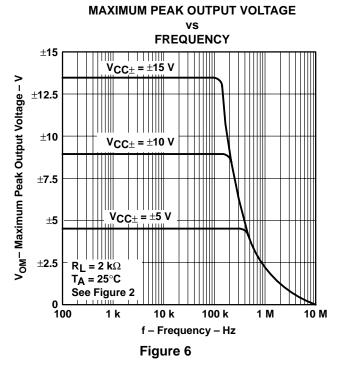
Table of Graphs

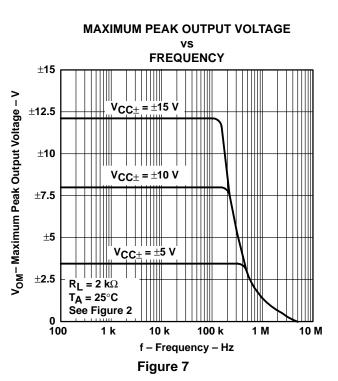
	FIGURE
Input bias current vs Free-air temperature	5
Maximum peak output voltage vs Frequency	6, 7, 8
Maximum peak output voltage vs Free-air temperature	9
Maximum peak output voltage vs Load resistance	10
Maximum peak output voltage vs Supply voltage	11
Large-signal differential voltage amplification vs Free-air temperature	12
Differential voltage amplification vs Frequency with feed-forward compensation	13
Large-signal differential voltage amplification and phase shift vs Frequency	14
Normalized unity-gain bandwidth and phase shift vs Free-air temperature	15
Common-mode rejection ratio vs Free-air temperature	16
Supply current vs Supply voltage	17
Supply current vs Free-air temperature	18
Total power dissipated vs Free-air temperature	19
Normalized slew rate vs Free-air temperature	20
Equivalent input noise voltage vs Frequency	21
Total harmonic distortion vs Frequency	22
Voltage-follower large-signal pulse response	23
Output voltage vs Elapsed time	24

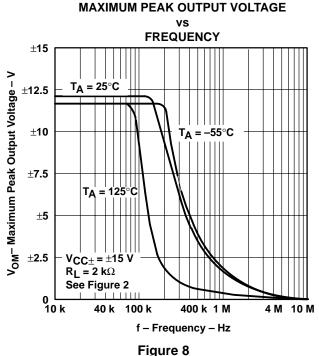


TYPICAL CHARACTERISTICS[†]





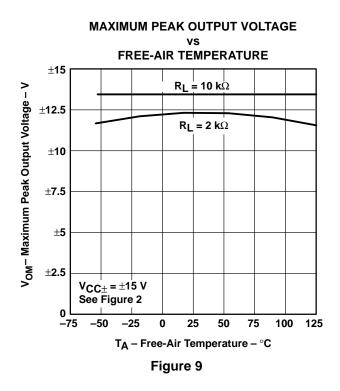


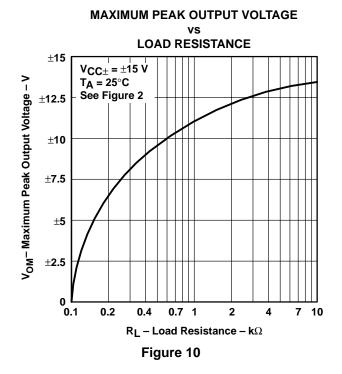


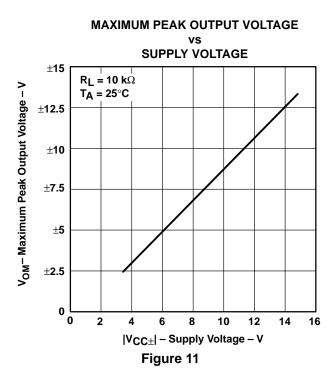
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. An 18-pF compensation capacitor is used.

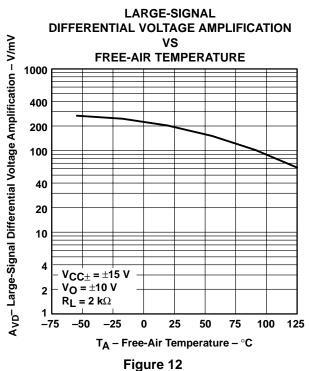


TYPICAL CHARACTERISTICS[†]









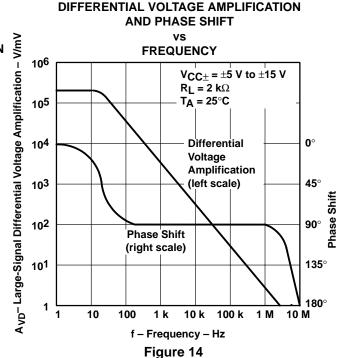
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. An 18-pF compensation capacitor is used.



LARGE-SIGNAL

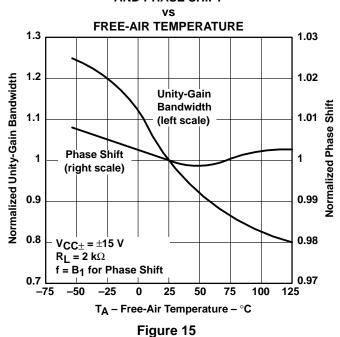
TYPICAL CHARACTERISTICS[†]

DIFFERENTIAL VOLTAGE AMPLIFICATION FREQUENCY WITH FEED-FORWARD COMPENSATION 106 A_{VD}- Differential Voltage Amplification - dB 10⁵ 104 10³ 102 $V_{CC\pm} = \pm 15 V$ C2 = 3 pF101 T_A = 25°C See Figure 3 100 1 k 10 k 100 k 1 M 100 M f - Frequency - Hz



NORMALIZED UNITY-GAIN BANDWIDTH AND PHASE SHIFT

Figure 13



COMMON-MODE REJECTION RATIO

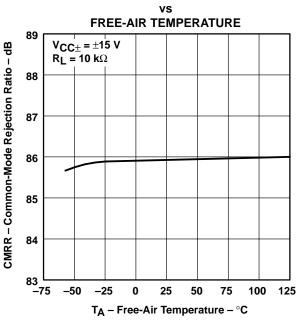
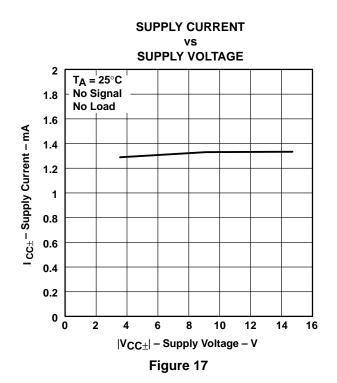


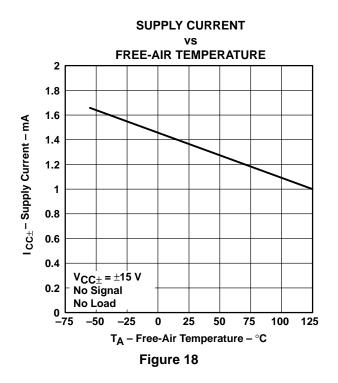
Figure 16

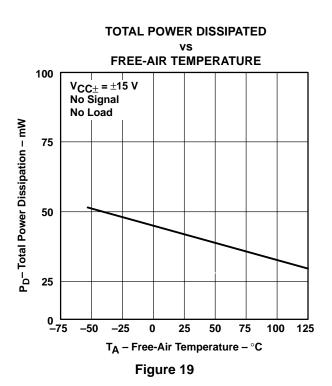
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. An 18-pF compensation capacitor is used.

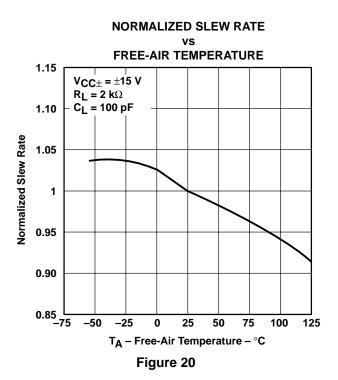


TYPICAL CHARACTERISTICS[†]





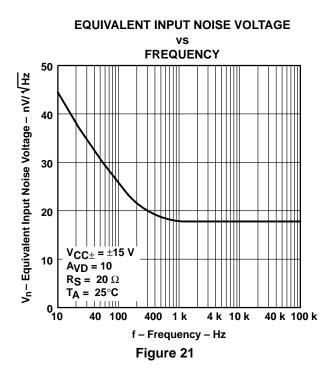


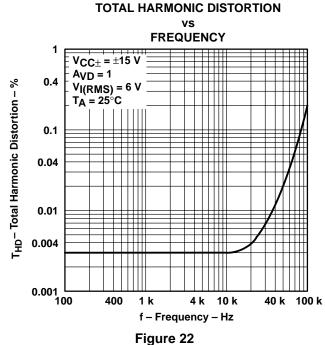


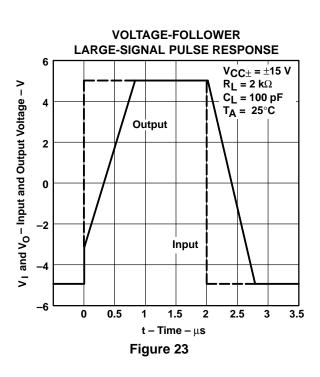
[†] Data at high and low temperatures are applicable only within the rated operating free-air temperature ranges of the various devices. An 18-pF compensation capacitor is used.

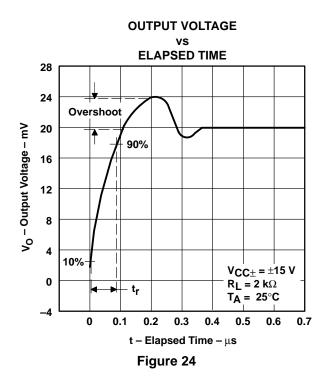


TYPICAL CHARACTERISTICS









APPLICATION INFORMATION

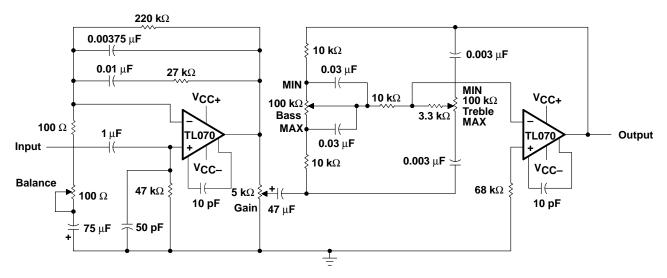


Figure 25. IC Preamplifier

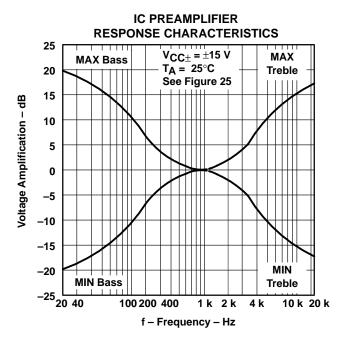


Figure 26



PACKAGE OPTION ADDENDUM

www.ti.com 7-Jun-2010

PACKAGING INFORMATION

Orderable Device	Status (1) P	ackage Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
TL070CD	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	Samples Not Available
TL070CP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI	Samples Not Available
TL070IP	OBSOLETE	PDIP	Р	8		TBD	Call TI	Call TI	Samples Not Available

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com	Wireless	www.ti.com/wireless-apps
RF/IF and ZigBee® Solutions	www.ti.com/lprf		

TI E2E Community Home Page

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated

e2e.ti.com